Ordering number:EN1422C

NPN Planar Silicon Transistor

2SC3294

Driver Applications

Applications

· Suitable for use in switching of L load (motor drivers, printer hammer drivers, relay drivers).

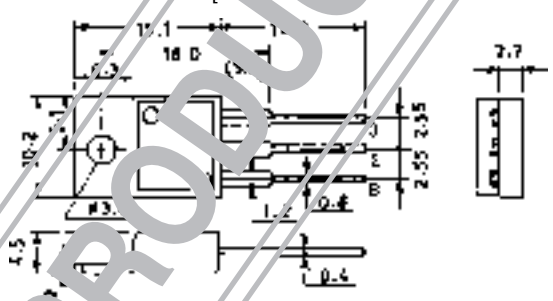
Features

· High DC current gain.
· Large current capacity and wide ASO.
· On-chip Zener diode of 60±10V between collector and base.
· Uniformity in collector-to-base breakdown voltage due to adoption of accurate impurity diffusion process.
· High inductive load handling capability.

Package Dimensions

unit:mm

2010C



1 : Base
2 : Collector
3 : Emitter

JEDEC : TO-220AB
EIAJ : SC-46

Specifications

Absolute Maximum Ratings at Ta = 25˚C

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	V_{CBO}		50*	V
Collector-to-Emitter Voltage	V_{CEO}		50*	V
Emitter-to-Base Voltage	V_{EBO}		6	V
Collector Current	I_C		3	A
Collector Current (Pulse)	I_{CP}		6	A
Base Current	I_B		0.6	A
Collector Dissipation	P_C	T_c=25˚C	25	W
Junction Temperature	Tj		150	˚C
Storage Temperature	Tstg		–55 to +150	˚C

* : With Zener diode (60±10V)

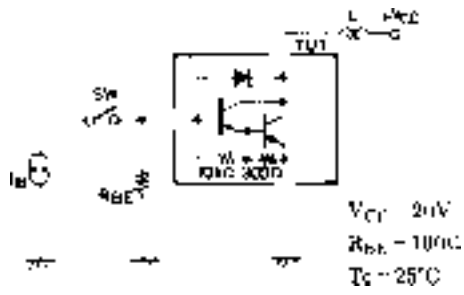
Electrical Characteristics at Ta = 25˚C

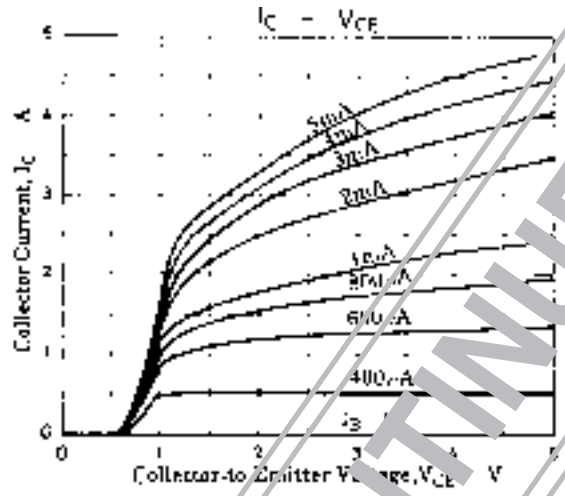
Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Collector Cutoff Current	I_{CBO}	V_{CB}=40V, I_E=0			10	μA
Emitter Cutoff Current	I_{EBO}	V_{EB}=5V, I_C=0			2	mA
DC Current Gain	h_{FE}	V_{CE}=5V, I_C=1.5A	1000	4000		
Gain-Bandwidth Product	f_T	V_{CE}=5V, I_C=1.5A		180		MHz
Collector-to-Emitter Saturation Voltage	$V_{CE(sat)}$	I_C=1.5A, I_B=6mA		1.0	1.5	V
Base-to-Emitter Saturation Voltage	$V_{BE(sat)}$	I_C=1.5A, I_B=6mA			2.0	V

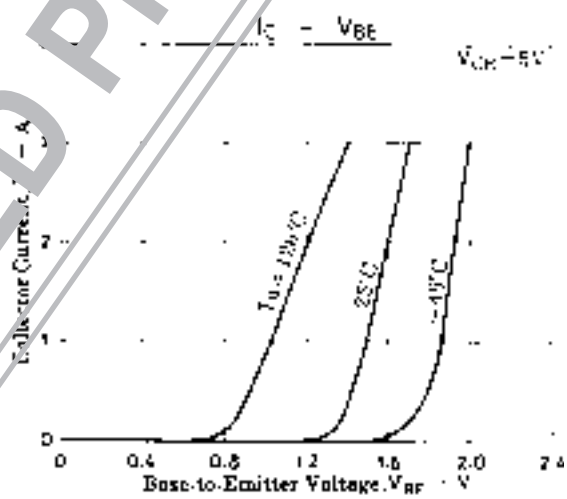
SANYO Electric Co.,Ltd. Semiconductor Bussiness Headquaters
TOKYO OFFICE Tokyo Bldg., 1-10, 1 Chome, Ueno, Taito-ku, TOKYO, 110-8534 JAPAN

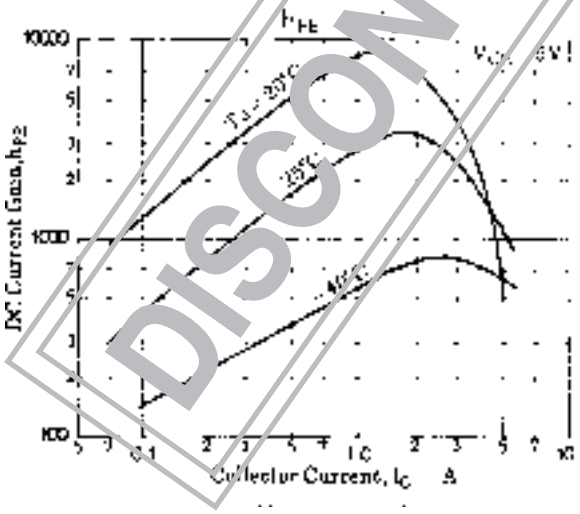
Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Collector-to-Base Breakdown Voltage	$V_{(BR)CBO}$	I_C=0.1mA, I_E=0	50	60	70	V
Collector-to-Emitter Breakdown Voltage	$V_{(BR)CEO}$	I_C=1mA, R_{BE}=∞	50	60	70	V
Inductive Load Handling Capability	Es/b	L=100mH, R_{BE}=100Ω	30			mJ

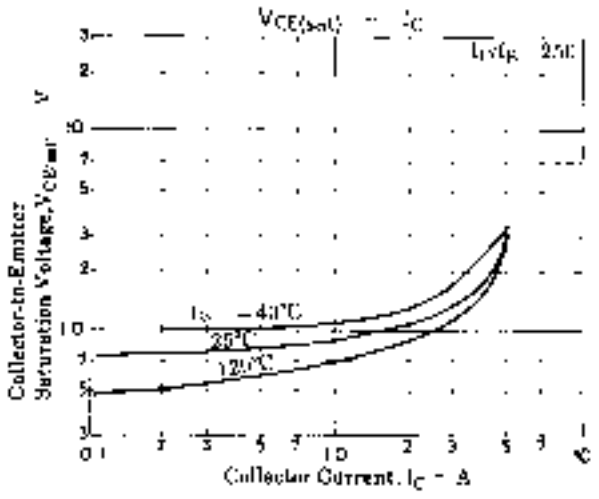
Es/b Test Circuit

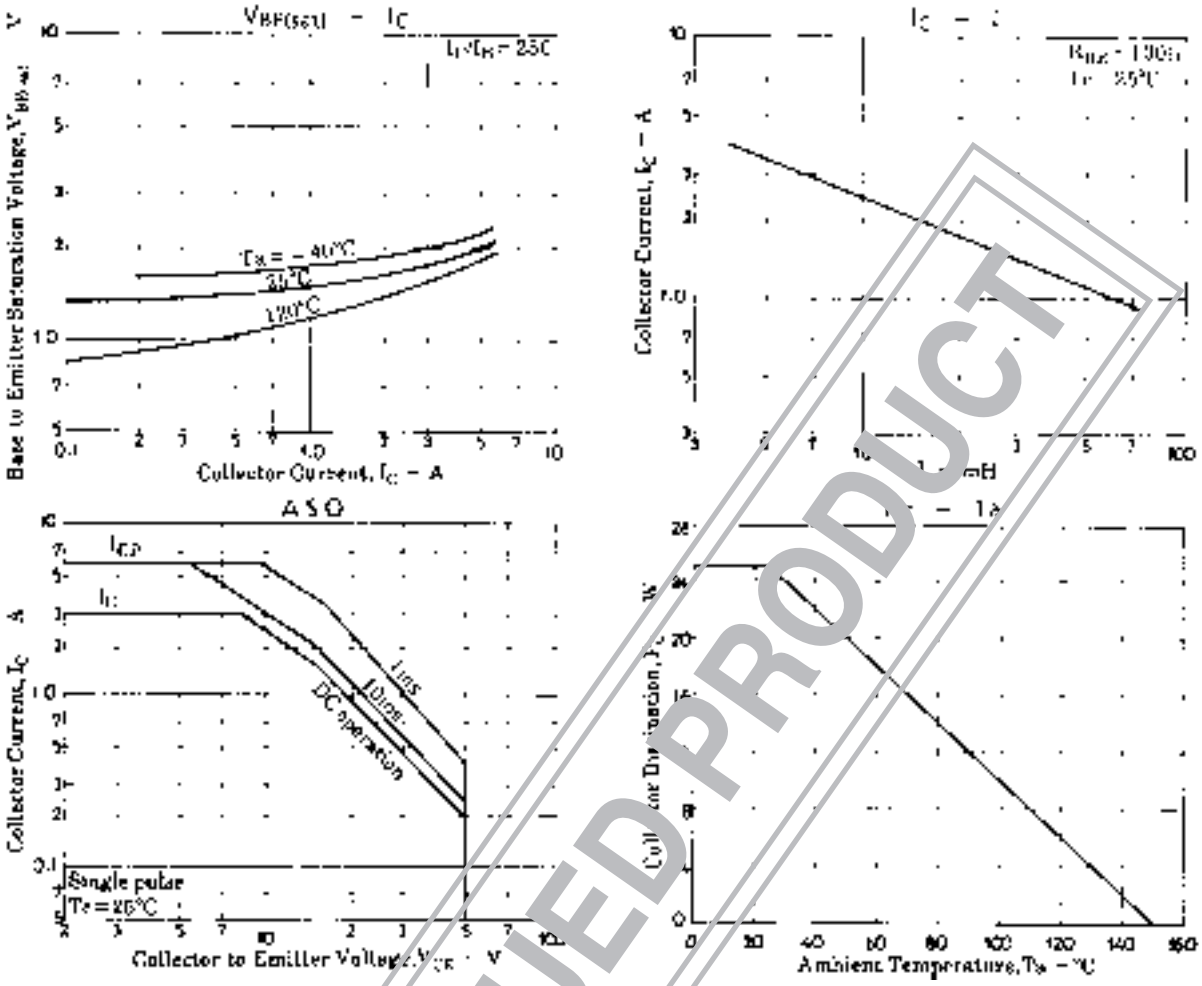












This catalog provides information as of November, 1998. Specifications and information herein are subject to change without notice.